## NSN 5961-01-426-5017

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View Online at https://aerobasegroup.com/nsn/5961-01-426-5017 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Terminal Length:** 1.195 inches **Overall Height:** 0.260 inches **Overall Width:** 0.545 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-254aa **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage **Current Rating Per Characteristic:** 8.00 amperes source current and 32.00 amperes off-state current, peak **Power Rating Per Characteristic:** 125.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/596 government specification Shelf Life: N/a **Unit Of Measure:** 

Fiig: A110a0

No

**Demilitarization:**